Silicon P Channel MOS Type (U-MOSII)/Silicon Epitaxial Schottky Barrier Diode

SSM5G11TU

DC-DC Converter Applications

- 4-V drive
- Combined a P-ch MOSFET and a Schottky barrier diode in one package.
- Low R_{DS (ON)} and Low V_F

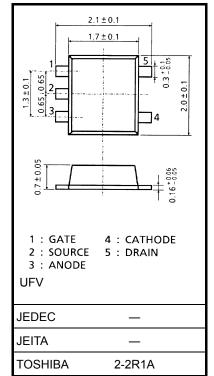
Absolute Maximum Ratings

MOSFET (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
Drain-source voltage		V _{DSS}	-30	V	
Gate-source voltage		V _{GSS}	±20	V	
Drain current	DC	I _D	-1.4	А	
	Pulse	I _{DP}	-2.8	A	
Drain power dissipation		P _D (Note 1)	500	mW	
Channel temperature		T _{ch}	150	°C	

Schottky Barrier Diode (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Repetitive peak reverse voltage	V _{RRM}	30	V
Average forward current	I _{F (AV)}	0.7	А
Peak one cycle surge forward current	I _{FSM}	2 (50Hz)	А
Junction temperature	Тј	125	°C



Weight: 7 mg (typ.)

MOSFET and Diode (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Storage temperature range	T _{stg}	-55 to125	°C

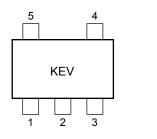
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

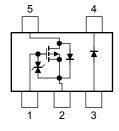
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Mounted on FR4 board (25.4 mm \times 25.4 mm \times 1.6 mm, Cu pad: 645 mm²)

Marking

Equivalent Circuit (top view)





2008-09-27

MOSFET

Electrical Characteristics (Ta = 25°C)

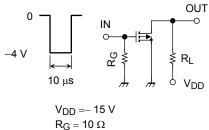
Chara	cteristics	Symbol	Test Conditions	Min	Тур.	Max	Unit
Drain-source breakdown voltage		V (BR) DSS	I _D = -1 mA, V _{GS} = 0 V	-30	_	_	V
		V (BR) DSX	$I_D = -1 \text{ mA}, V_{GS} = +20 \text{ V}$	-15	_	_	
Drain cutoff curren	ıt	I _{DSS}	$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	_	_	-10	μA
Gate leakage curre	ent	I _{GSS}	$V_{GS} = \pm 16$ V, $V_{DS} = 0$ V	_	_	±1	μA
Gate threshold vol	tage	V _{th}	V _{DS} = -5 V, I _D = -1 mA	-0.8		-2.0	V
Forward transfer a	dmittance	Y _{fs}	$V_{DS} = -5 V, I_D = -1.0 A$ (No	ote 2) 1.0	2.0	_	S
Drain-source ON-resistance		D		ote 2) —	175	226	mΩ
		R _{DS (ON)}	$I_D = -0.5 \text{ A}, V_{GS} = -4 \text{ V}$ (No	ote 2) —	290	403	
Input capacitance		C _{iss}		_	120	—	
Output capacitance		C _{oss}	V _{DS} = -15 V, V _{GS} = 0, f = 1 MHz	_	32	—	pF
Reverse transfer capacitance		C _{rss}			21	_	
Total gate charge Gate-source charge		Qg		_	2.9	_	nC
		Q _{gs}	V _{DS} = -15 V, I _D = -1.4 A		2.2	_	
Gate-drain charge		Q _{gd}	V _{GS} = -10 V		0.7	_	
Switching time	Turn-on time	t _{on}	V _{DD} = -15 V, I _D = -1 A,	_	12	—	
	Turn-off time	t _{off}	V_{GS} = 0 to -4 V, R_{G} = 10 Ω		8.5	—	ns
Drain-source forward voltage		V _{DSF}	$I_D = 1.4 \text{ A}, V_{GS} = 0 \text{ V}$ (Note 2	2) —	0.87	1.2	V

Note 2: Pulse test

Switching Time Test Circuit

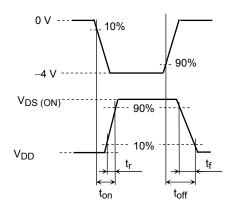
(a) Test Circuit

(b) V_{IN}



D.U. ≤ 1% V_{IN} : t_r , $t_f < 5$ ns Common Source Ta = 25°C

(c) V_{OUT}



Usage Considerations

Vth can be expressed as voltage between gate and source when the low operating current value is ID = 1 mA for this product. For normal switching operation, V_{GS (on)} requires a higher voltage than V_{th} and V_{GS (off)} requires a lower voltage than V_{th}.

(The relationship can be established as follows: $V_{GS\;(off)} < V_{th} < V_{GS\;(on)})$ Be sure to take this into consideration when using the device.

Schottky Barrier Diode

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Peak forward voltage	V _{FM (1)}	I _F = 0.5 A	_	0.34	0.41	V
Peak forward voltage	V _{FM (2)}	I _F = 0.7 A	_	0.37	0.44	V
Repetitive peak reverse current	I _{RRM}	V _R = 15 V	_	60	200	μA
Junction capacitance	CT	V _R = 0 V, f = 1 MHz	_	139	_	pF

Precaution

The Schottky barrier diode in this device has large reverse current leakage compared to typical switching diodes. Thus, excessive operating temperature or voltage may cause thermal runaway. To avoid this problem, be sure to take both forward and reverse loss into consideration.

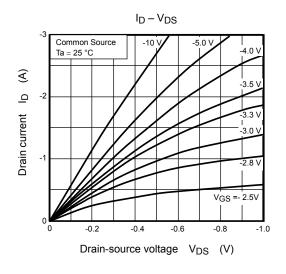
Handling Precaution

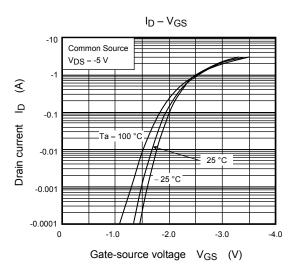
When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

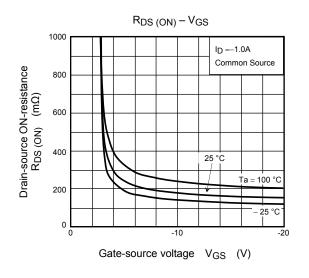
The Channel-to-Ambient thermal resistance $R_{th (ch-a)}$ and the drain power dissipation P_D vary according to the board material, board area, board thickness and pad area. When using this device, be sure to take heat dissipation fully into account.

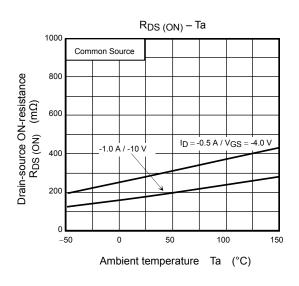
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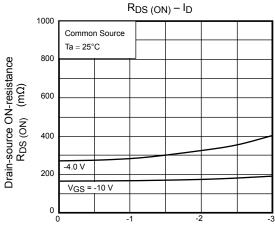
MOSFET



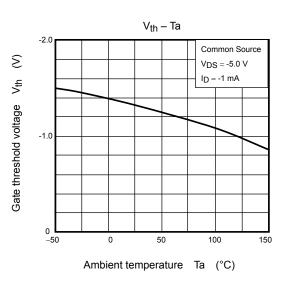






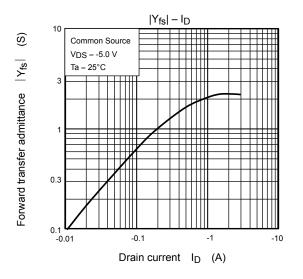


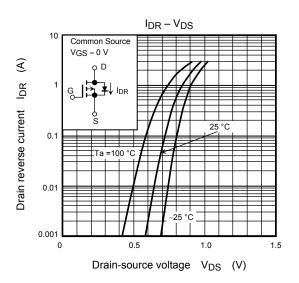
Drain current ID (A)

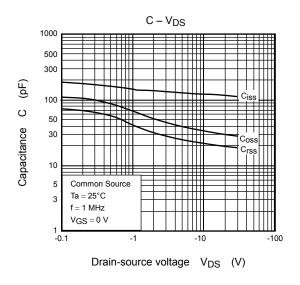


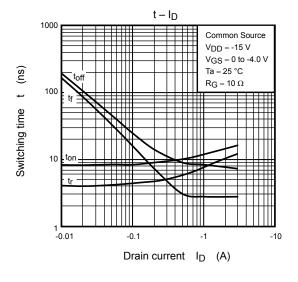
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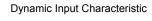
MOSFET

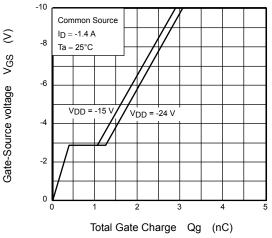






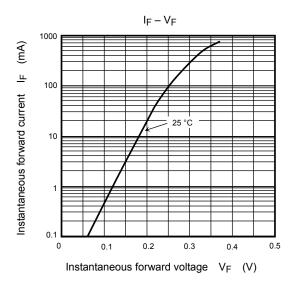


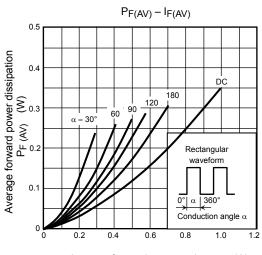




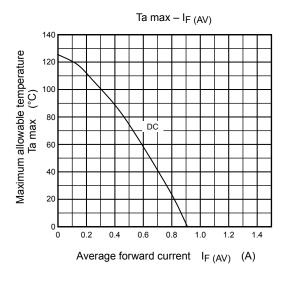
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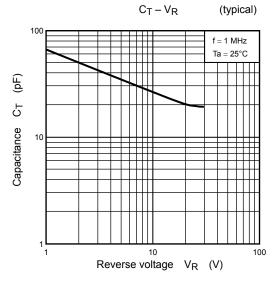
Schottky Barrier Diode





Average forward current $I_{F(AV)}$ (A)

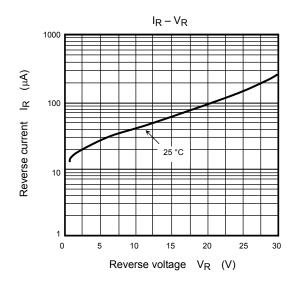


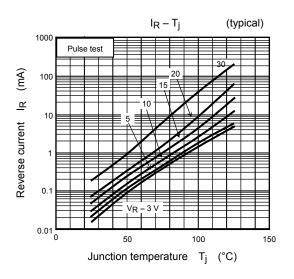


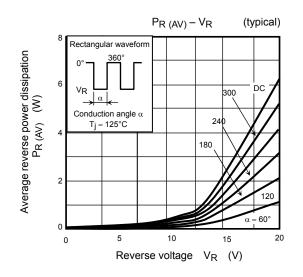
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Shottky Barrier Diode







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